

ELEC2208 Power Electronics and Drives

Tutorial 2 - Transistor, Heating & Cooling

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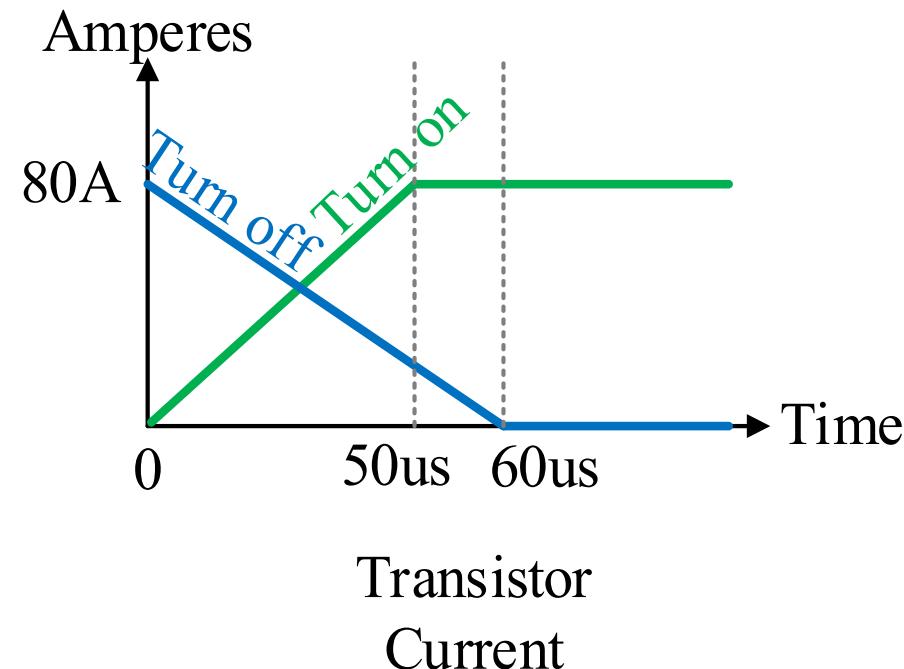
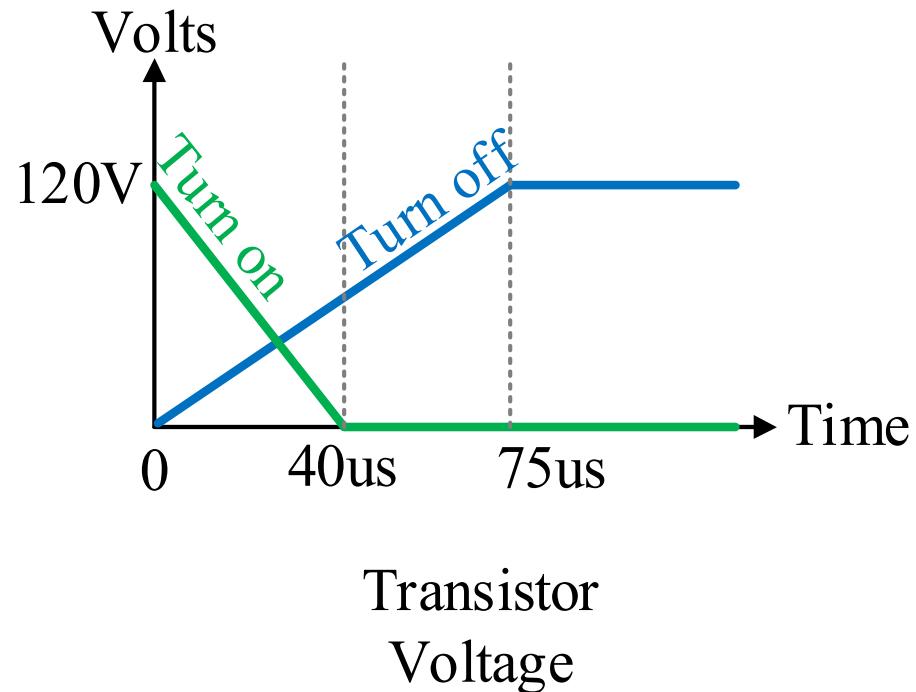
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59/4219

Question 1

A transistor has the switching characteristic shown below. If the mean power loss in the transistor is limited to 200 W, what is the maximum switching rate that can be achieved?



Mean power loss in transistor

When power loss occurs in a transistor?

(1) OFF state

Voltage: finite, Current ~ 0

$$P_{\text{off}} \sim 0$$

(2) ON state

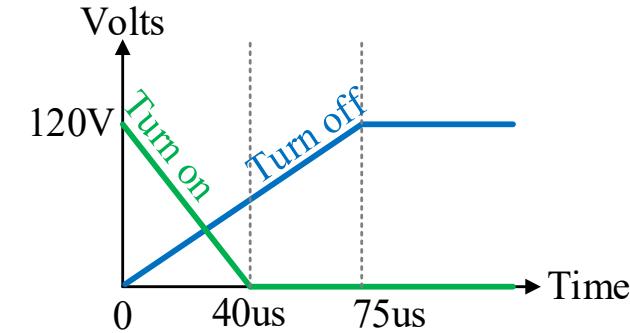
Current: finite, Voltage ~ 0

$$(R \sim m\Omega)$$

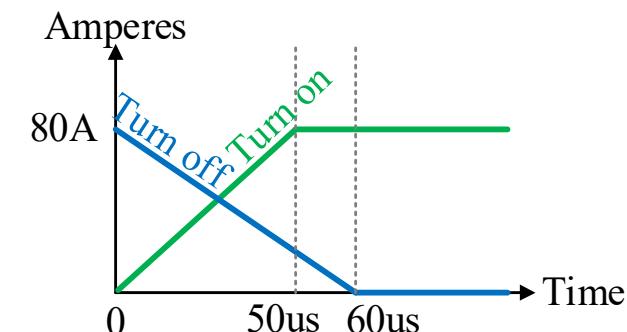
$$P_{\text{on}} \sim 0$$

(3) Switching state

Major power loss!



Transistor
Voltage



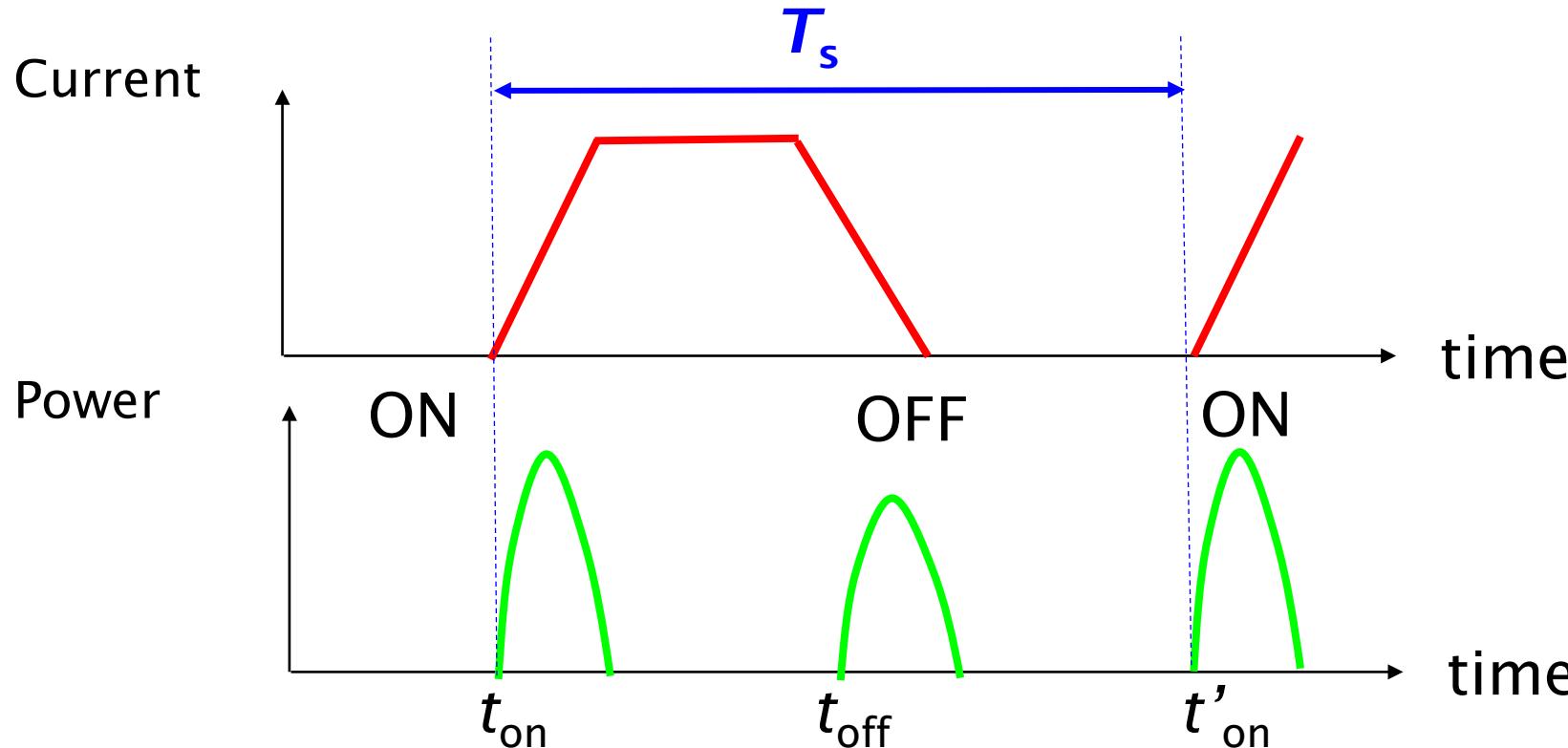
Transistor
Current

Mean power loss in transistor

“Mean”

To take an average over a period

Switching rate = Switching frequency f_s
Switching period $T_s = 1/f_s$



P_{on} calculation

$$P_{mean} = \frac{1}{T_s} \int_0^{T_s} \{P_{on}(t) + P_{off}(t)\} dt$$

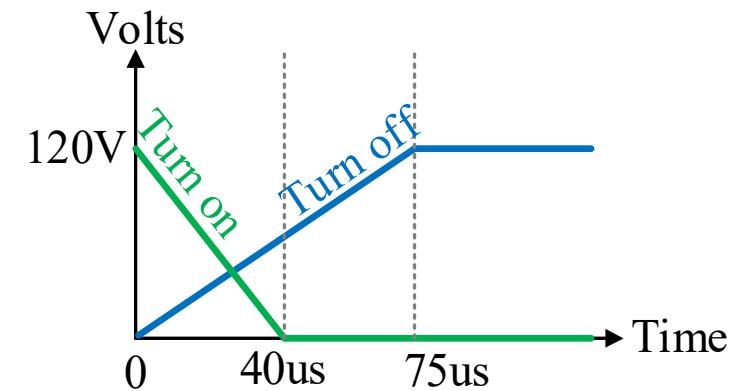
Calculation of P_{on}

$$P_{on}(t) = v_{on}(t)i_{on}(t)$$

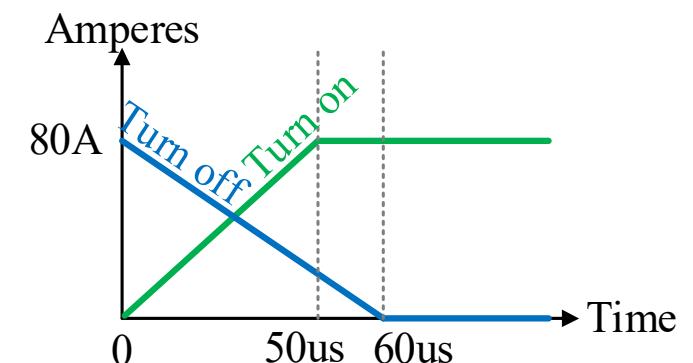
$$v_{on}(t) = -(3 \times 10^6)t + 120 \quad (t - t_{on} < 40 \mu s)$$

$$i_{on}(t) = (1.6 \times 10^6)t \quad (t - t_{on} < 50 \mu s)$$

$$P_{on} = -(4.8 \times 10^{12})t^2 + (1.92 \times 10^8)t \quad (t - t_{on} < 40 \mu s)$$



Transistor
Voltage



Transistor
Current



P_{off} calculation

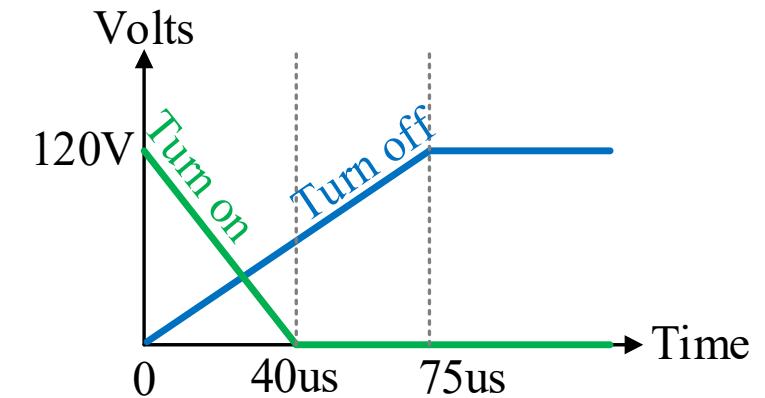
Calculation of P_{off}

$$P_{\text{off}}(t) = V_{\text{off}}(t)i_{\text{off}}(t)$$

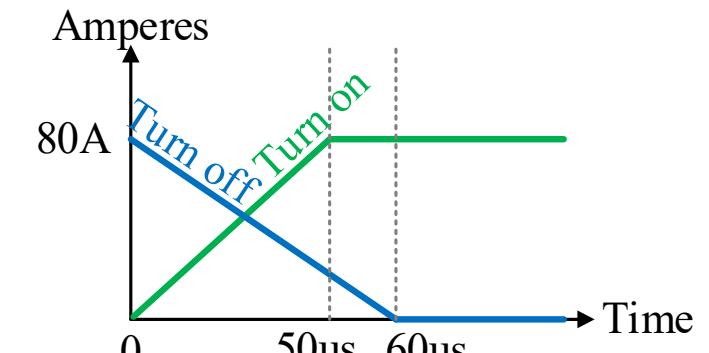
$$V_{\text{off}}(t) = (1.6 \times 10^6)t \quad (t - t_{\text{off}} < 75 \mu\text{s})$$

$$i_{\text{off}}(t) = -(1.3333 \times 10^6)t + 80 \quad (t - t_{\text{off}} < 60 \mu\text{s})$$

$$P_{\text{off}} = -(2.1333 \times 10^{12})t^2 + (1.28 \times 10^8)t \quad (t - t_{\text{off}} < 60 \mu\text{s})$$



Transistor
Voltage



Transistor
Current



Mean power loss in transistor

$$P_{mean} = \frac{1}{T_s} \int_0^{T_s} \{P_{on}(t) + P_{off}(t)\} dt$$

$$= \frac{1}{T_s} \int_0^{40 \times 10^{-6}} \{-(4.8 \times 10^{12})t^2 + (1.92 \times 10^8)t\} dt$$

$$+ \frac{1}{T_s} \int_0^{60 \times 10^{-6}} \{-(2.1333 \times 10^{12})t^2 + (1.28 \times 10^8)t\} dt$$

$$= \frac{1}{T_s} [-1.6 \times 10^{12}t^3 + 0.96 \times 10^8t^2]_0^{40 \times 10^{-6}}$$

$$+ \frac{1}{T_s} [-0.7111 \times 10^{12}t^3 + 0.64 \times 10^8t^2]_0^{60 \times 10^{-6}}$$

Mean power loss in transistor

$$P_{mean} = \frac{1}{T_s} \int_0^{T_s} \{P_{on}(t) + P_{off}(t)\} dt$$
$$= \frac{1}{T_s} \{(-0.1024 + 0.1536) + (-0.1536 + 0.2304)\}$$

$$= \frac{0.128}{T_s} \leq 200 \text{ (W)}$$

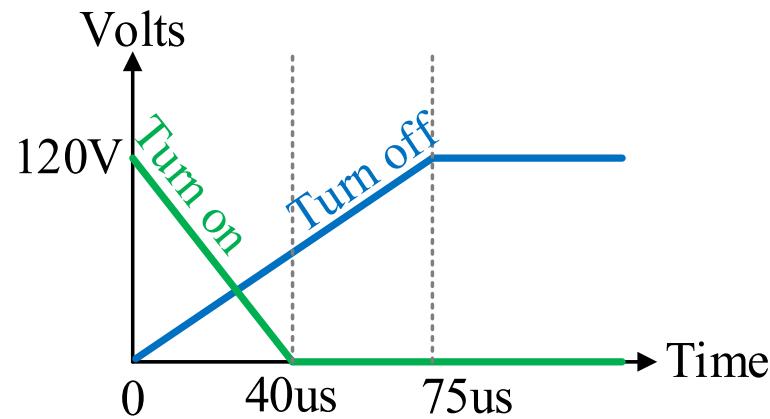
$$f_s = \frac{1}{T_s} \leq 200 \div 0.128 = 1562.5$$

$$\mathbf{f_{s(max)} = 1562.5 \text{ Hz} = 1.5625 \text{ kHz}} \quad (T_{s(min)} = 640 \mu\text{s})$$

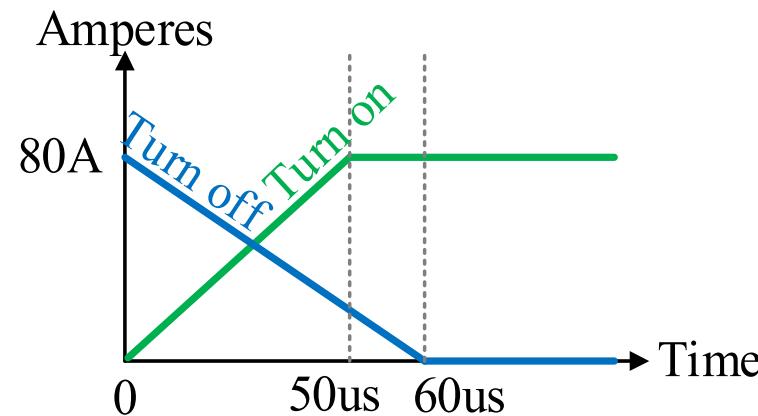


Question 2

For the transistor above (in Question 1), plot curves showing the instantaneous power during turn on and turn off. Find the maximum instantaneous power level developed.



Transistor
Voltage



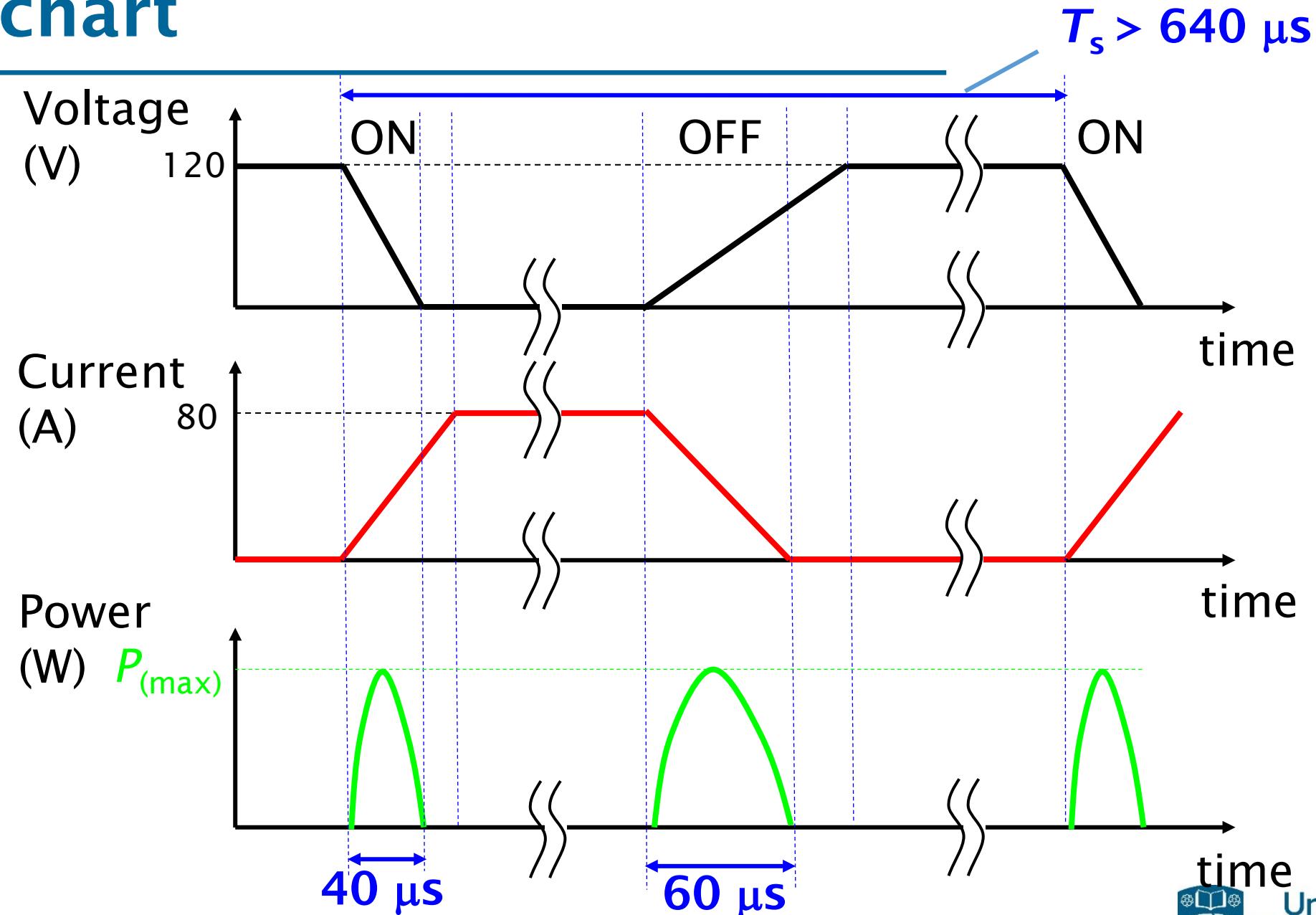
Transistor
Current



Let us draw a time chart.



Time chart



University of

Southampton

$P_{\text{on(max)}}$ Calculation

$$P_{\text{on}} = -(4.8 \times 10^{12})t^2 + (1.92 \times 10^8)t$$

$$\frac{dP_{\text{on}}}{dt} = (-9.6 \times 10^{12})t + 1.92 \times 10^8 = 0$$

$$t = \frac{1.92 \times 10^8}{9.6 \times 10^{12}} = 2.0 \times 10^{-5} = 20 \mu\text{s}$$

$$\begin{aligned} P_{\text{on(max)}} &= -(4.8 \times 10^{12}) \times (20 \times 10^{-6})^2 + (1.92 \times 10^8) \times (20 \times 10^{-6}) \\ &= 1920 \text{ W} \end{aligned}$$



$P_{\text{off(max)}}$ Calculation

$$P_{\text{off}} = -(2.1333 \times 10^{12})t^2 + (1.28 \times 10^8)t$$

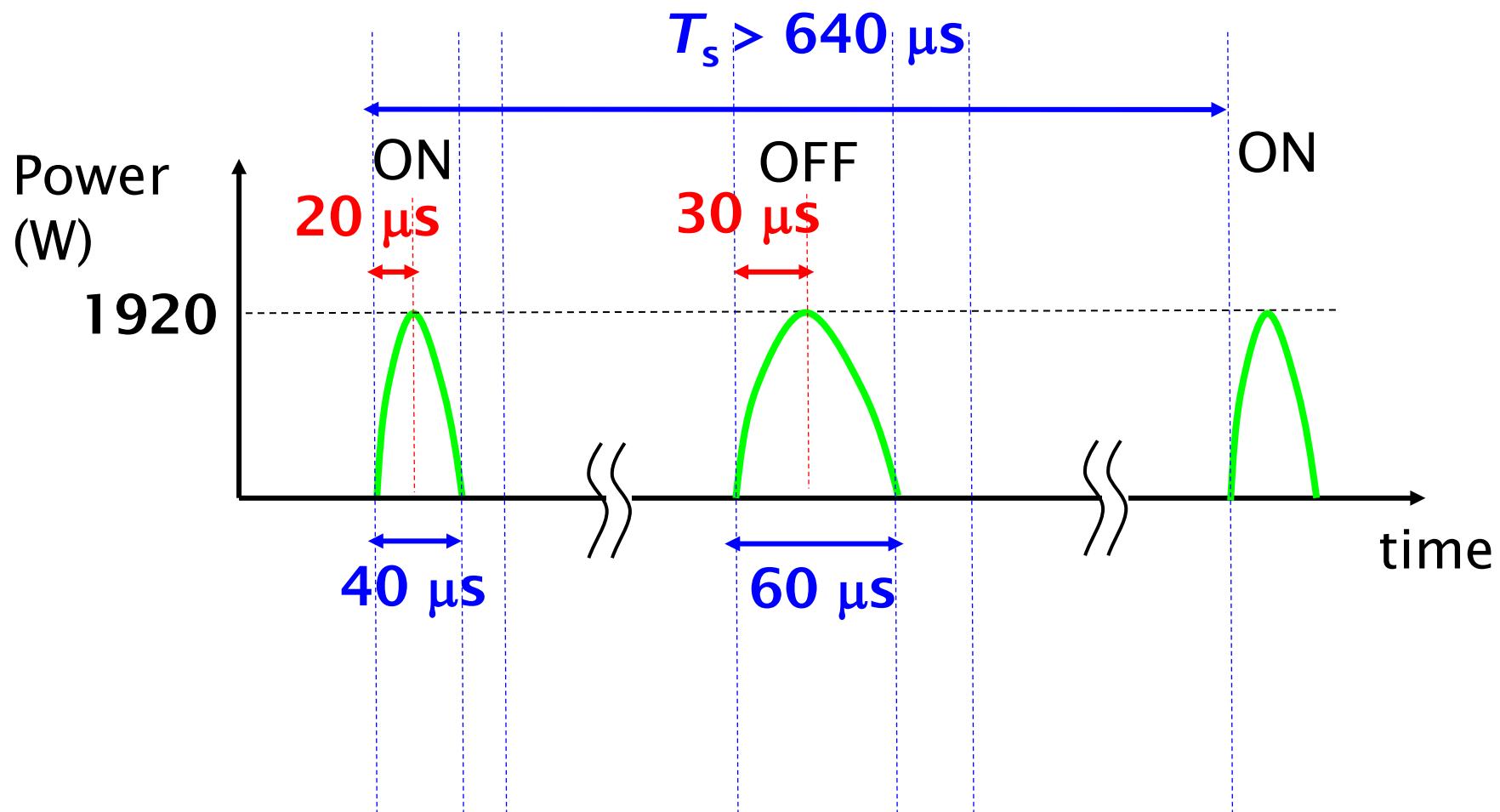
$$\frac{dP_{\text{off}}}{dt} = (-4.2666 \times 10^{12})t + 1.28 \times 10^8 = 0$$

$$t = \frac{1.28 \times 10^8}{4.2666 \times 10^{12}} = 3.0 \times 10^{-5} = 30 \mu\text{s}$$

$$\begin{aligned} P_{\text{off(max)}} &= -(2.1333 \times 10^{12}) \times (30 \times 10^{-6})^2 + (1.28 \times 10^8) \times (30 \times 10^{-6}) \\ &= 1920 \text{ W} \end{aligned}$$



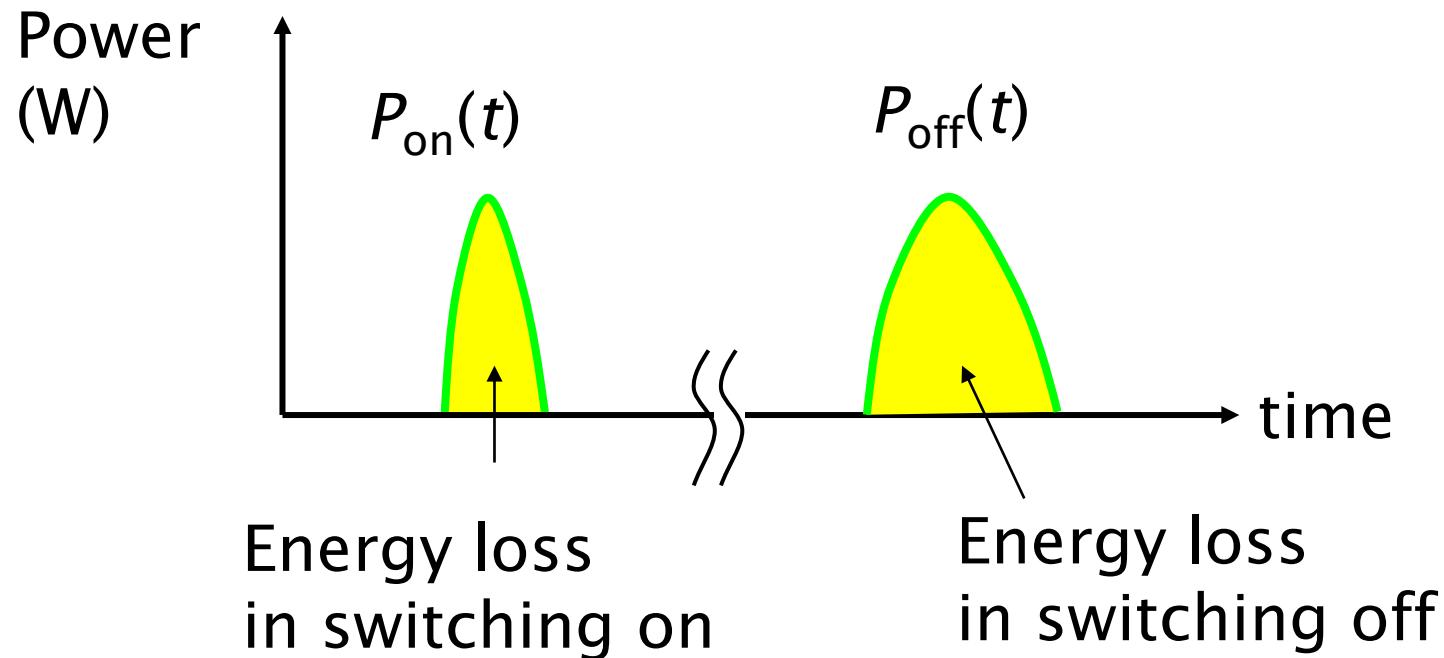
Instantaneous power curve



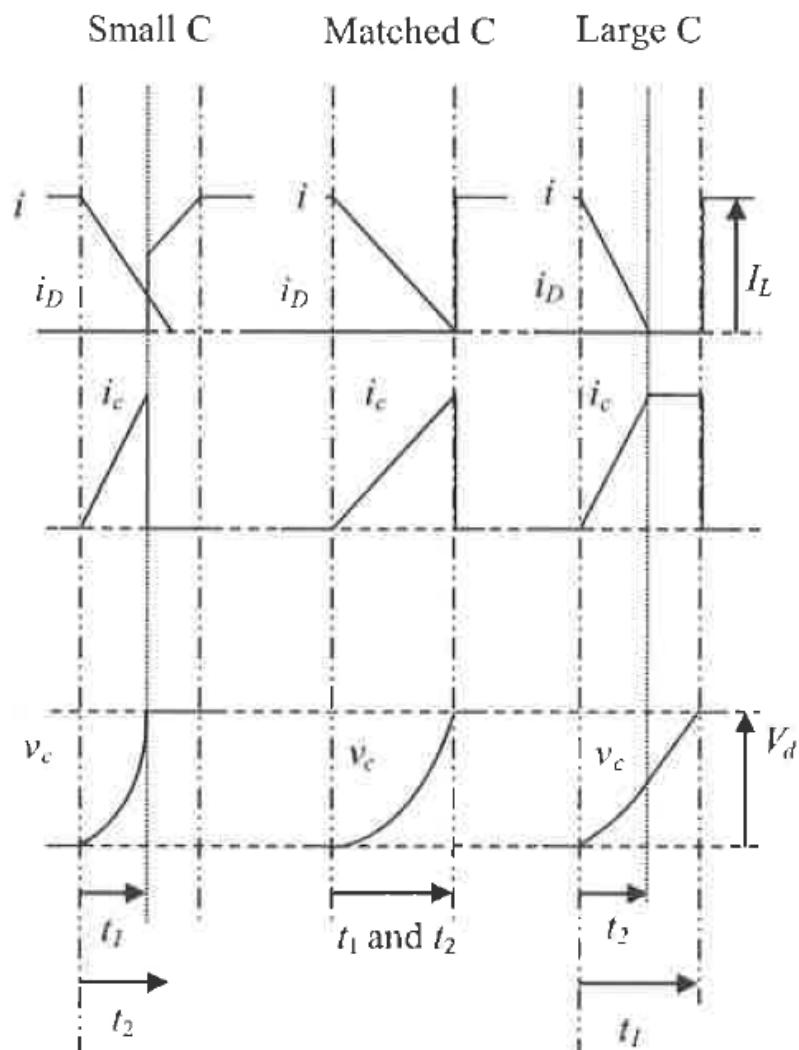
Energy loss in switching

$$P_{mean} = \frac{1}{T_s} \int_0^{T_s} \{P_{on}(t) + P_{off}(t)\} dt$$

Energy (J)



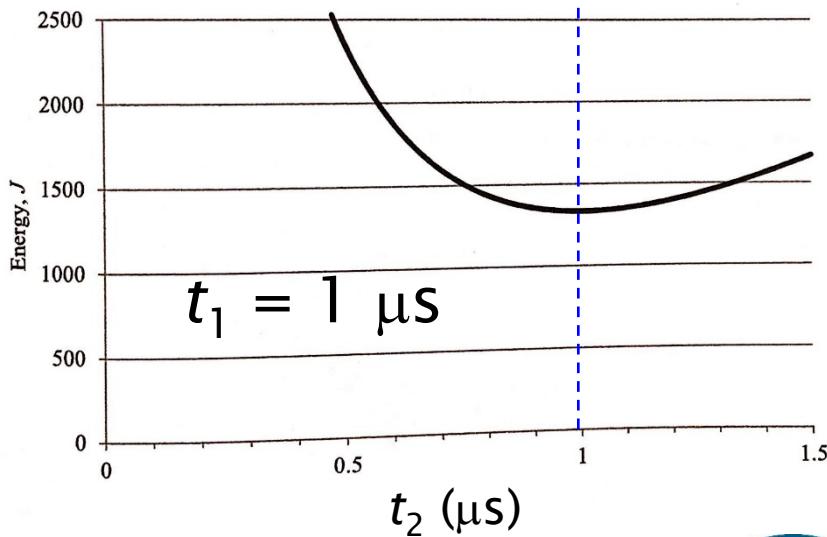
Energy loss in switching



Energy loss in switching off of the transistor snubber.

$$E = V_d I_L \left[\frac{t_2}{2} - \frac{2t_1}{3} + \frac{t_1^2}{2t_2} \right]$$

→ Minimum at $t_2 = t_1$



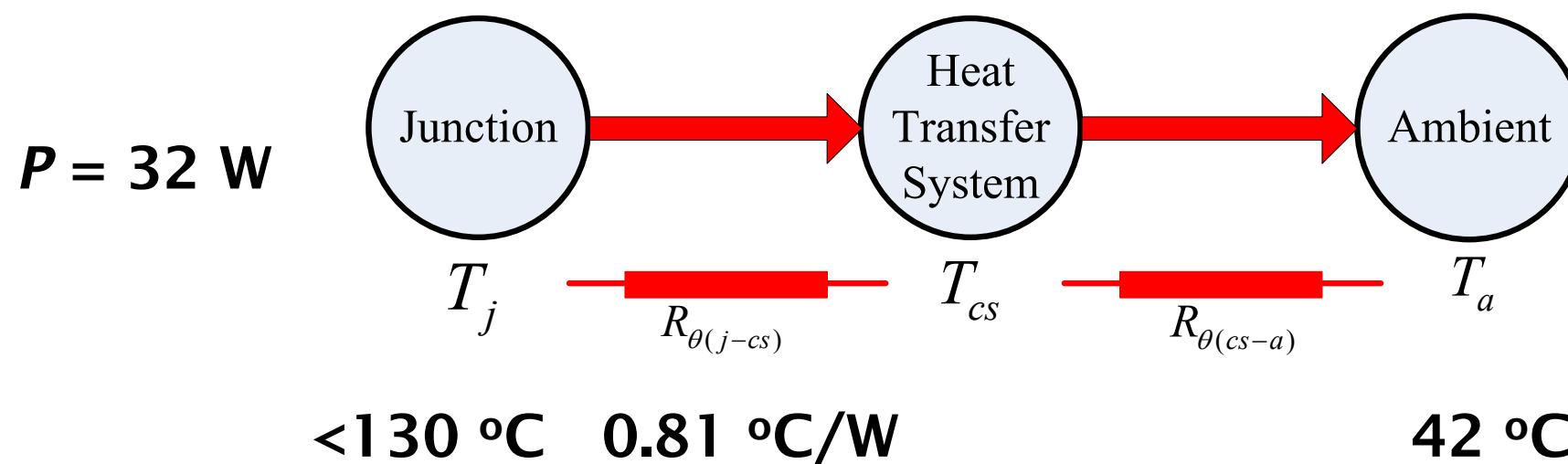
Question 3

A thyristor is operating with a steady-state power loss of 32 W. If the thermal resistance from the junction to the heat transfer system is $0.81 \text{ } ^\circ\text{C/W}$, what will be the thyristor base temperature if the junction temperature is not exceed $130 \text{ } ^\circ\text{C}$ at an ambient temperature of $42 \text{ } ^\circ\text{C}$?

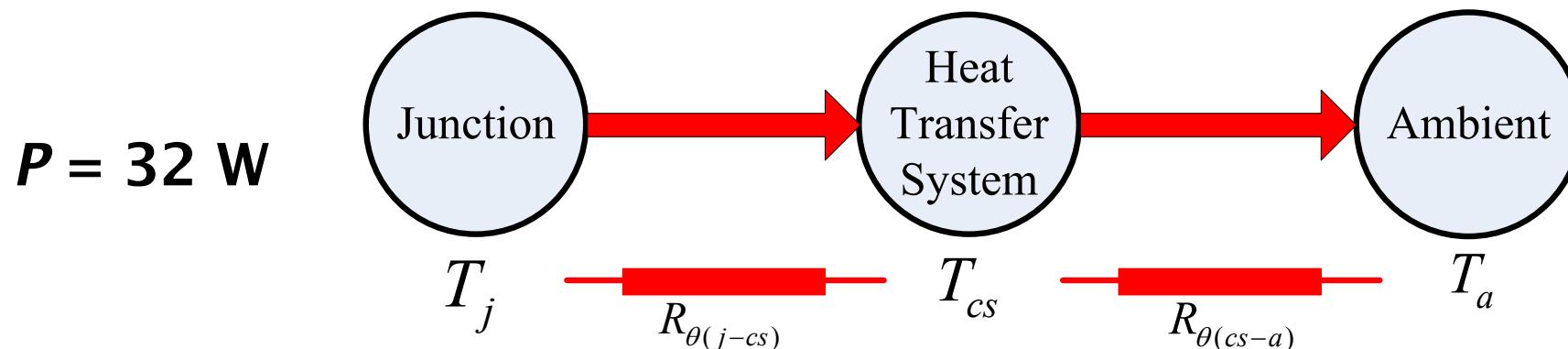


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Answer 3



$$P = 32 \text{ W}$$

$$<130 \text{ }^{\circ}\text{C} \quad 0.81 \text{ }^{\circ}\text{C/W}$$

$$\Delta T = T_j - T_{cs} = PR_{\theta(j-cs)}$$

$$T_j = PR_{\theta(j-cs)} + T_{CS} = 32 \times 0.81 + T_{CS} = 25.92 + T_{CS} < 130$$

$$T_{CS} < 130 - 25.92 = 104.08$$

$$T_{CS} < 104.08 \text{ }^{\circ}\text{C}$$



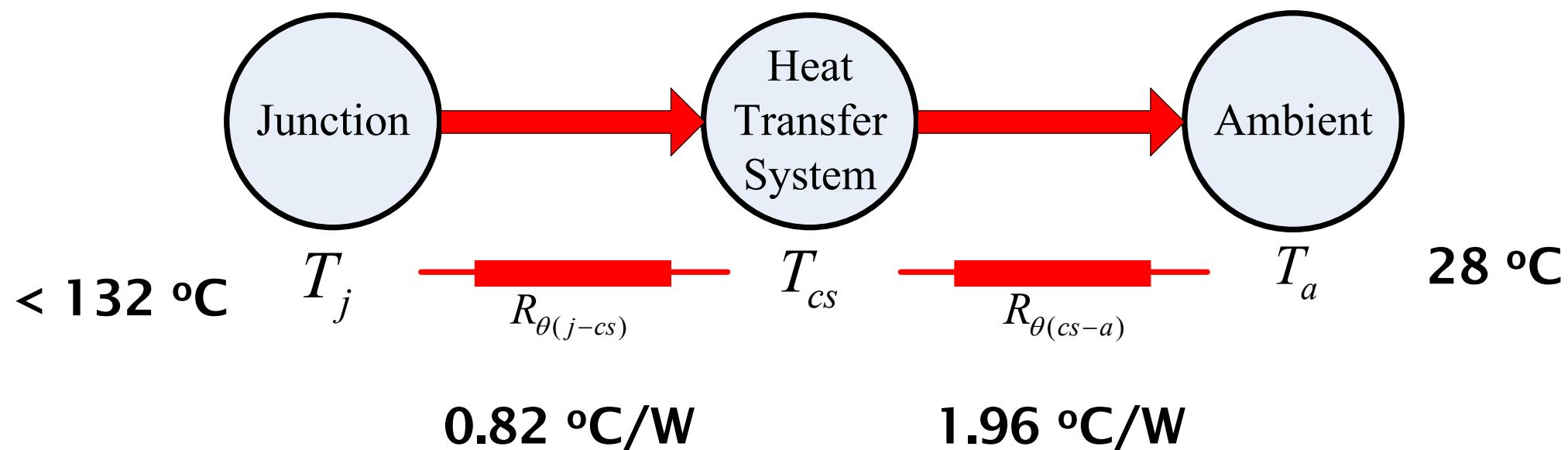
Question 4

A thyristor has a thermal resistance of $0.82 \text{ } ^\circ\text{C/W}$ between its junction and the heat transfer system and $1.96 \text{ } ^\circ\text{C/W}$ between the heat transfer system and the ambient temperature. What will be the maximum allowable power loss in the thyristor if the junction temperature is to be kept below $132 \text{ } ^\circ\text{C}$ for an ambient temperature of $28 \text{ } ^\circ\text{C}$.

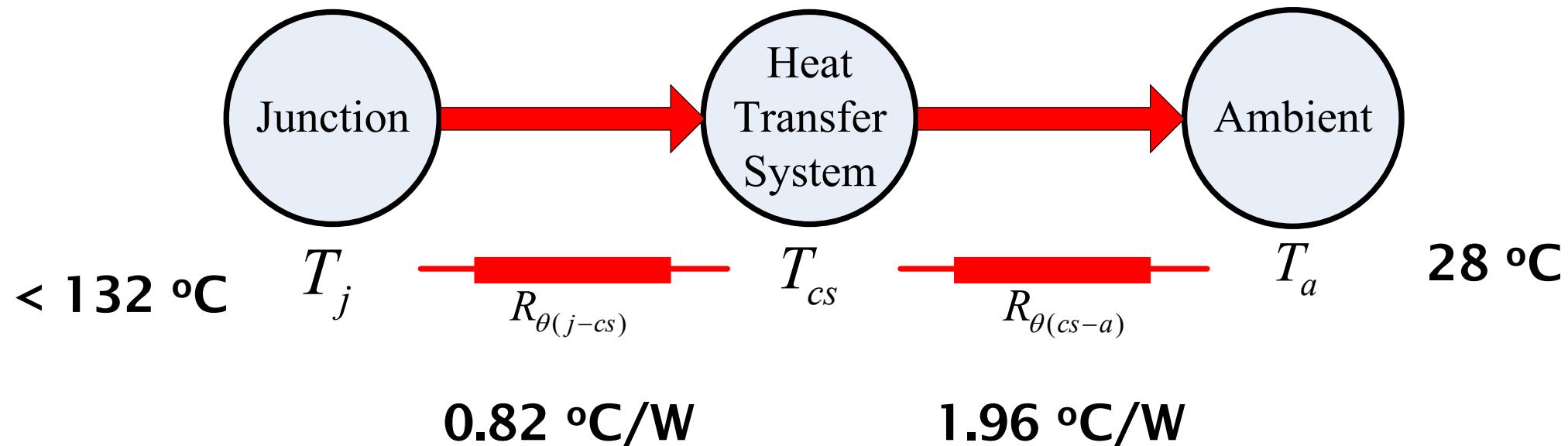


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Answer 4



$$R_{\theta(\text{total})} = R_{\theta(j-cs)} + R_{\theta(cs-a)} = 0.82 + 1.96 = 2.78$$

$$\Delta T = T_j - T_a = PR_{\theta(\text{total})}$$

$$T_j = PR_{\theta(\text{total})} + T_a = P \times 2.78 + 28 < 132$$

$$P < 37.410 \text{ W}$$

